

16K

X20C16

2K x 8 Bit

High Speed AUTOSTORE™ NOVRAM

FEATURES

- **Fast Access Time:** 35ns, 45ns, 55ns
- **High Reliability**
 - Endurance:** 1,000,000 Nonvolatile Store Operations
 - Retention:** 100 Years Minimum
- **AUTOSTORE™ NOVRAM**
 - Automatically Stores RAM Data Into the E²PROM Array When V_{CC} Low Threshold is Detected
 - User Enabled Option
 - Open Drain AUTOSTORE Status Output Pin
- **Power-on Recall**
 - E²PROM Data Automatically Recalled Into RAM Upon Power-up
- **Software Data Protection**
 - Locks Out Inadvertent Store Operations
- **Low Power CMOS**
 - Standby: 250µA
- **Infinite E²PROM Array Recall, and RAM Read and Write Cycles**

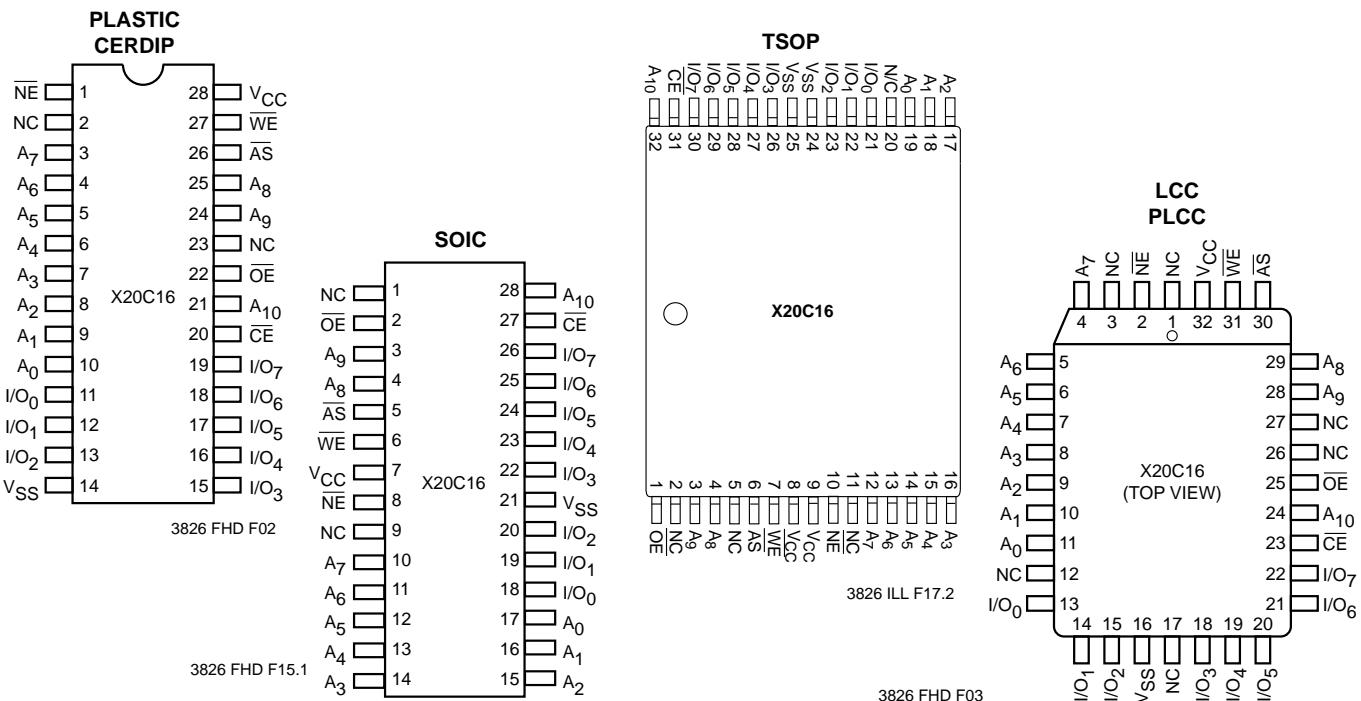
DESCRIPTION

The Xicor X20C16 is a 2K x 8 NOVRAM featuring a high-speed static RAM overlaid bit-for-bit with a nonvolatile electrically erasable PROM (E²PROM) and the AUTOSTORE feature which automatically saves the RAM contents to E²PROM at power-down. The X20C16 is fabricated with advanced CMOS floating gate technology to achieve high speed with low power and wide power-supply margin. The X20C16 features a compatible JEDEC approved pinout for byte-wide memories, for industry standard RAMs, ROMs, EPROMs, and E²PROMs.

The NOVRAM design allows data to be easily transferred from RAM to E²PROM (store) and E²PROM to RAM (recall). The store operation is completed in 5ms or less and the recall operation is completed in 10µs or less. An automatic array recall operation reloads the contents of the E²PROM into RAM upon power-up.

Xicor NOVRAMS are designed for unlimited write operations to RAM, either from the host or recalls from E²PROM, and a minimum 1,000,000 store operations to the E²PROM. Data retention is specified to be greater than 100 years.

PIN CONFIGURATION



AUTOSTORE™ NOVRAM is a trademark of Xicor, Inc.

X20C16

PIN DESCRIPTIONS

Addresses (A₀–A₁₀)

The Address inputs select an 8-bit memory location during a read or write operation.

Chip Enable (\overline{CE})

The Chip Enable input must be LOW to enable all read/write operations. When \overline{CE} is HIGH, power consumption is reduced.

Output Enable (\overline{OE})

The Output Enable input controls the data output buffers and is used to initiate read and recall operations. Output Enable LOW disables a store operation regardless of the state of \overline{CE} , \overline{WE} , or \overline{NE} .

Data In/Data Out (I/O₀–I/O₇)

Data is written to or read from the X20C16 through the I/O pins. The I/O pins are placed in the high impedance state when either \overline{CE} or \overline{OE} is HIGH or when \overline{NE} is LOW.

Write Enable (\overline{WE})

The Write Enable input controls the writing of data to the static RAM.

Nonvolatile Enable (\overline{NE})

The Nonvolatile Enable input controls the recall function to the E²PROM array.

AUTOSTORE Output (\overline{AS})

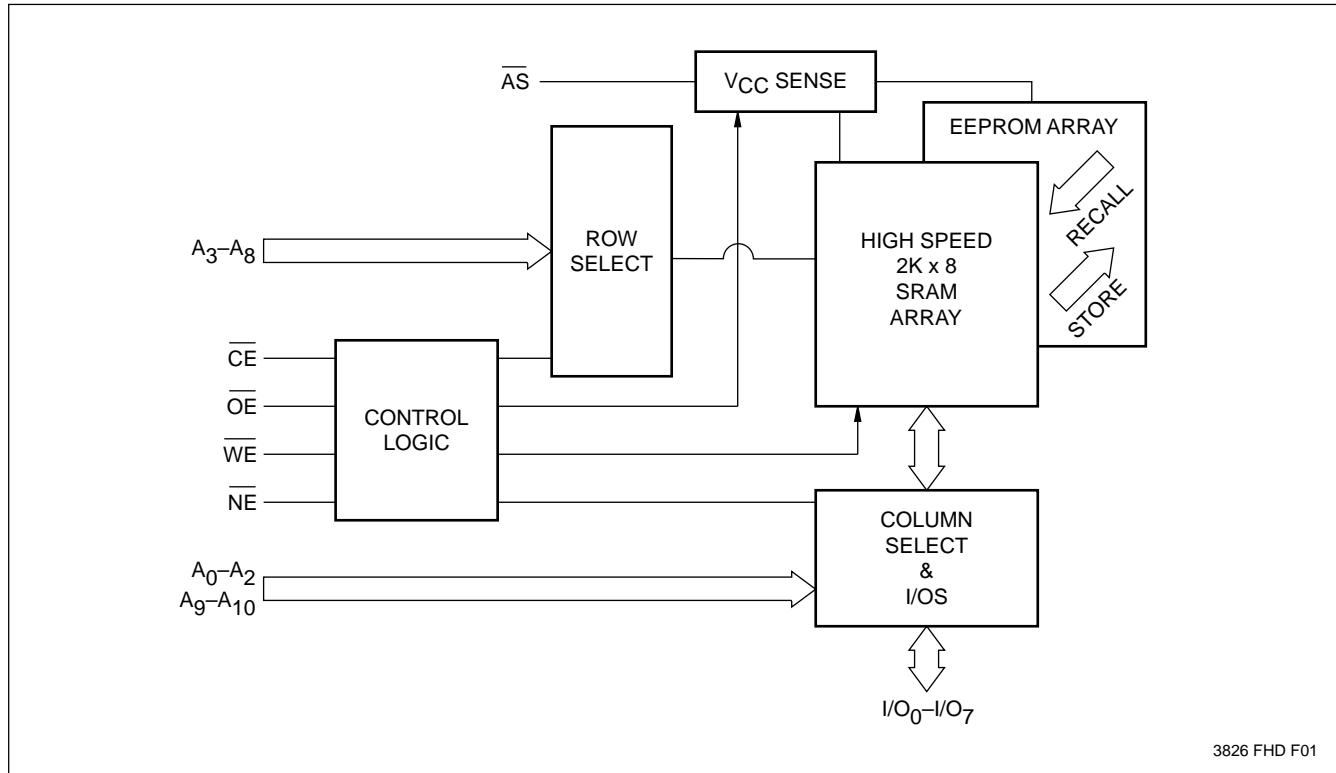
\overline{AS} is an open drain output which, when asserted indicates V_{CC} has fallen below the AUTOSTORE threshold (V_{ASTH}). \overline{AS} may be wire-ORed with multiple open drain outputs and used as an interrupt input to a microcontroller.

PIN NAMES

Symbol	Description
A ₀ –A ₁₀	Address Inputs
I/O ₀ –I/O ₇	Data Input/Output
\overline{WE}	Write Enable
\overline{CE}	Chip Enable
\overline{OE}	Output Enable
\overline{NE}	Nonvolatile Enable
\overline{AS}	AUTOSTORE Output
V _{CC}	+5V
V _{SS}	Ground
NC	No Connect

3826 PGM T01

FUNCTIONAL DIAGRAM



X20C16

DEVICE OPERATION

The \overline{CE} , \overline{OE} , \overline{WE} , and \overline{NE} inputs control the X20C16 operation. The X20C16 byte-wide NOVRAM uses a 2-line control architecture to eliminate bus contention in a system environment. The I/O bus will be in a high impedance state when either \overline{OE} or \overline{CE} is HIGH, or when \overline{NE} is LOW.

RAM Operations

RAM read and write operations are performed as they would be with any static RAM. A read operation requires \overline{CE} and \overline{OE} to be LOW with \overline{WE} and \overline{NE} HIGH. A write operation requires \overline{CE} and \overline{WE} to be LOW with \overline{NE} HIGH. There is no limit to the number of read or write operations performed to the RAM portion of the X20C16.

Memory Transfer Operations

There are two memory transfer operations: a recall operation whereby the data stored in the E²PROM array is transferred to the RAM array; and a store operation which causes the entire contents of the RAM array to be stored in the E²PROM array.

Recall operations are performed automatically upon power-up and under host system control when \overline{NE} , \overline{OE} and \overline{CE} are LOW and \overline{WE} is HIGH. The recall operation takes a maximum of 5μs.

SDP (Software Data Protection)

There are two methods of initiating a store operation. The first is the software store command. This command takes the place of the hardware store employed on the X20C04. This command is issued by entering into the special command mode: \overline{NE} , \overline{CE} , and \overline{WE} strobe LOW while at the same time a specific address and data combination is sent to the device. This is a three step operation: the first address/data combination is 555[H]/AA[H]; the second combination is 2AA[H]/55[H]; and the final command combination is 555[H]/33[H]. This sequence of pseudo write operations will immediately initiate a store operation. Refer to the software command timing diagrams for details on set and hold times for the various signals.

The second method of storing data is with the AUTOSTORE command. When enabled, data is auto-

matically stored from the RAM into the E²PROM array whenever V_{CC} falls below the preset Autostore threshold. This feature is enabled by performing the first two steps for the software store with the command combination being 555[H]/CC[H].

The AUTOSTORE feature is disabled by issuing the three step command sequence with the command combination being 555[H]/CD[H]. The AUTOSTORE feature will also be reset if V_{CC} falls below the power-up reset threshold (approximately 3.5V) and is then raised back into the operation range.

Write Protection

The X20C16 supports two methods of protecting the nonvolatile data.

- If after power-up the AUTOSTORE feature is not enabled, no AUTOSTORE can occur.
- V_{CC} Sense – All functions are inhibited when V_{CC} is $\leq 3.0V$ typical.

SYMBOL TABLE

The following symbol table provides a key to understanding the conventions used in the device timing diagrams. The diagrams should be used in conjunction with the device timing specifications to determine actual device operation and performance, as well as device suitability for user's application.

WAVEFORM	INPUTS	OUTPUTS
	Must be steady	Will be steady
	May change from LOW to HIGH	Will change from LOW to HIGH
	May change from HIGH to LOW	Will change from HIGH to LOW
	Don't Care: Changes Allowed	Changing: State Not Known
	N/A	Center Line is High Impedance

X20C16

ABSOLUTE MAXIMUM RATINGS*

Temperature under Bias -65°C to $+135^{\circ}\text{C}$
 Storage Temperature -65°C to $+150^{\circ}\text{C}$
 Voltage on any Pin with
 Respect to V_{SS} -1V to $+7\text{V}$
 D.C. Output Current 10mA
 Lead Temperature (Soldering, 10 seconds) 300°C

RECOMMENDED OPERATING CONDITIONS

Temperature	Min.	Max.
Commercial	0°C	$+70^{\circ}\text{C}$
Industrial	-40°C	$+85^{\circ}\text{C}$
Military	-55°C	$+125^{\circ}\text{C}$

3826 PGM T02.1

*COMMENT

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and the functional operation of the device at these or any conditions other than those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Supply Voltage	Limits
X20C16	$5\text{V} \pm 10\%$

3826 PGM T03.1

D.C. OPERATING CHARACTERISTICS (Over recommended operating conditions unless otherwise specified.)

Symbol	Parameter	Limits			Test Conditions
		Min.	Max.	Units	
I_{CC1}	V_{CC} Current (Active)		100	mA	$\overline{NE} = \overline{WE} = V_{IH}, \overline{CE} = \overline{OE} = V_{IL}$ Address Inputs = $0.4\text{V}/2.4\text{V}$ Levels $@ f = 20\text{MHz}$ All I/Os = Open
I_{CC2}	V_{CC} Current During Store		5	mA	All Inputs = V_{IH}
$I_{CC3}^{(2)}$	V_{CC} Current During AUTOSTORE		2.5	mA	All I/Os = Open
I_{SB1}	V_{CC} Standby Current (TTL Input)		10	mA	$\overline{CE} = V_{IH}$, All Other Inputs = V_{IH} All I/Os = Open
I_{SB2}	V_{CC} Standby Current (CMOS Input)		250	μA	All Inputs = $V_{CC} - 0.3\text{V}$ All I/Os = Open
I_{LI}	Input Leakage Current		10	μA	$V_{IN} = V_{SS}$ to V_{CC}
I_{LO}	Output Leakage Current		10	μA	$V_{OUT} = V_{SS}$ to $V_{CC}, \overline{CE} = V_{IH}$
$V_{IL}^{(1)}$	Input LOW Voltage	-1	0.8	V	
$V_{IH}^{(1)}$	Input HIGH Voltage	2	$V_{CC} + 0.5$	V	
V_{OL}	Output LOW Voltage		0.4	V	$I_{OL} = 4\text{mA}$
V_{OLAS}	AUTOSTORE Output		0.4	V	$I_{OLAS} = 1\text{mA}$
V_{OH}	Output HIGH Voltage	2.4		V	$I_{OH} = -4\text{mA}$

3826 PGM T04.3

POWER-UP TIMING

Symbol	Parameter	Max.	Units
$t_{PUR}^{(2)}$	Power-Up to RAM Operation	100	μs
$t_{PUW}^{(2)}$	Power-Up to Nonvolatile Operation	5	ms

3826 PGM T05

CAPACITANCE $T_A = +25^{\circ}\text{C}$, $f = 1\text{MHz}$, $V_{\text{CC}} = 5\text{V}$.

Symbol	Test	Max.	Units	Conditions
$C_{I/O}^{(2)}$	Input/Output Capacitance	10	pF	$V_{I/O} = 0\text{V}$
$C_{IN}^{(2)}$	Input Capacitance	6	pF	$V_{IN} = 0\text{V}$

3826 PGM T06.1

Notes: (1) V_{IL} min. and V_{IH} max. are for reference only and are not tested.

(2) This parameter is periodically sampled and not 100% tested.

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ENDURANCE AND DATA RETENTION

Parameter	Min.	Units
Endurance	100,000	Data Changes Per Bit
Store Cycles	1,000,000	Store Cycles
Data Retention	100	Years

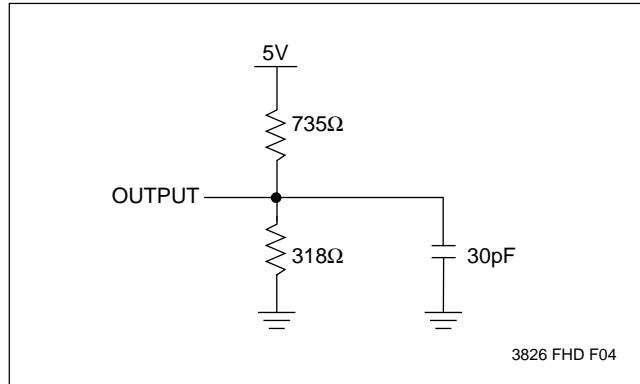
3826 PGM T07.1

MODE SELECTION

CE	WE	NE	OE	Mode	I/O	Power
H	X	X	X	Not Selected	Output High Z	Standby
L	H	H	L	Read RAM	Output Data	Active
L	L	H	X	Write "1" RAM	Input Data High	Active
L	L	H	X	Write "0" RAM	Input Data Low	Active
L	H	L	L	Array Recall	Output High Z	Active
L	L	L	H	Software Command	Input Data	Active
L	H	H	H	Output Disabled	Output High Z	Active
L	L	L	L	Not Allowed	Output High Z	Active
L	H	L	H	No Operation	Output High Z	Active

3826 PGM T09

EQUIVALENT A.C. LOAD CIRCUIT



A.C. CONDITIONS OF TEST

Input Pulse Levels	0V to 3V
Input Rise and Fall Times	5ns
Input and Output Timing Levels	1.5V

3826 PGM T08.1

X20C16

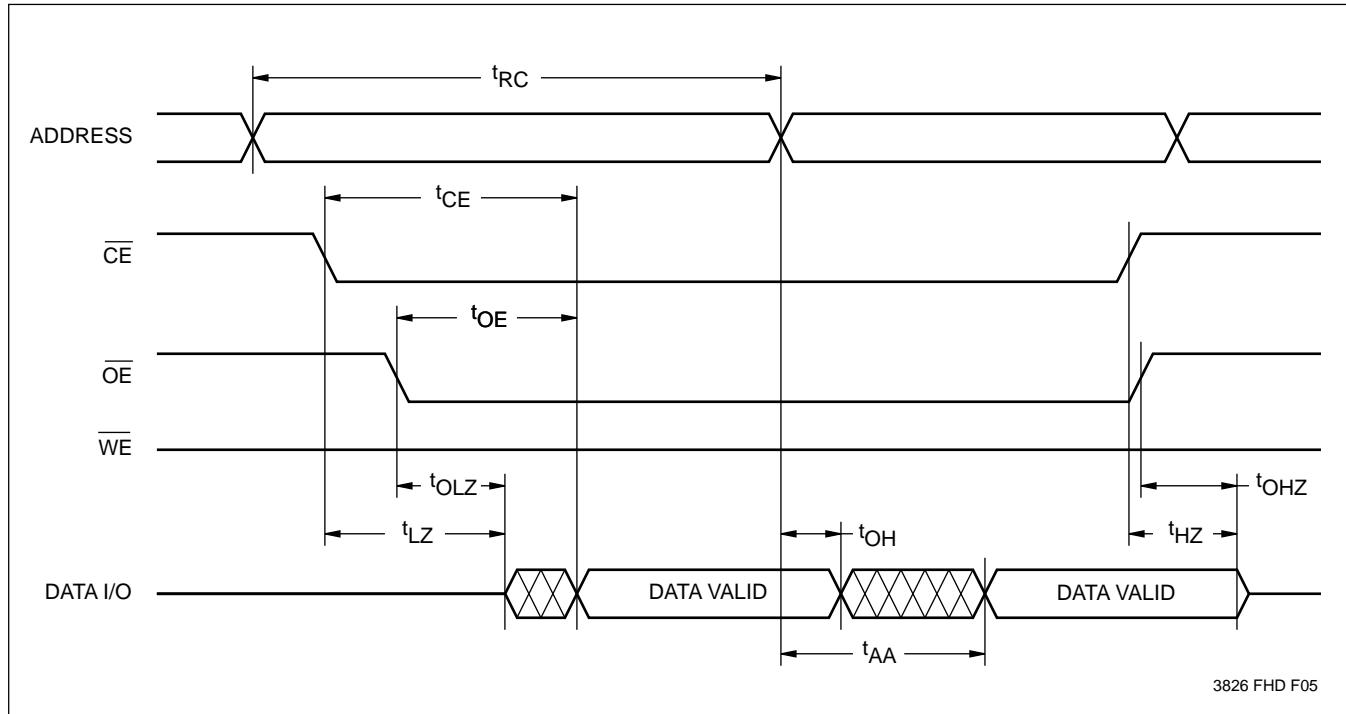
A.C. CHARACTERISTICS (Over the recommended operating conditions unless otherwise specified)

Read Cycle Limits

Symbol	Parameter	X20C16-35		X20C16-45		X20C16-55		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
t_{RC}	Read Cycle Time	35		45		55		ns
t_{CE}	Chip Enable Access Time			35		45		ns
t_{AA}	Address Access Time			35		45		ns
t_{OE}	Output Enable Access Time			20		25		ns
$t_{LZ}^{(3)}$	Chip Enable to Output in Low Z	0		0		0		ns
$t_{OLZ}^{(3)}$	Output Enable to Output in Low Z	0		0		0		ns
$t_{HZ}^{(3)}$	Chip Disable to Output in High Z	0	15	0	20	0	25	ns
$t_{OHZ}^{(3)}$	Output Disable to Output in High Z	0	15	0	20	0	25	ns
t_{OH}	Output Hold From Address Change	0		0		0		ns

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Read Cycle



3826 FHD F05

Note: (3) t_{LZ} min., t_{HZ} , t_{OLZ} min., and t_{OHZ} are periodically sampled and not 100% tested. t_{HZ} max. and t_{OHZ} max. are measured, with $C_L = 5\text{pF}$, from the point when \overline{CE} or \overline{OE} return HIGH (whichever occurs first) to the time when the outputs are no longer driven.

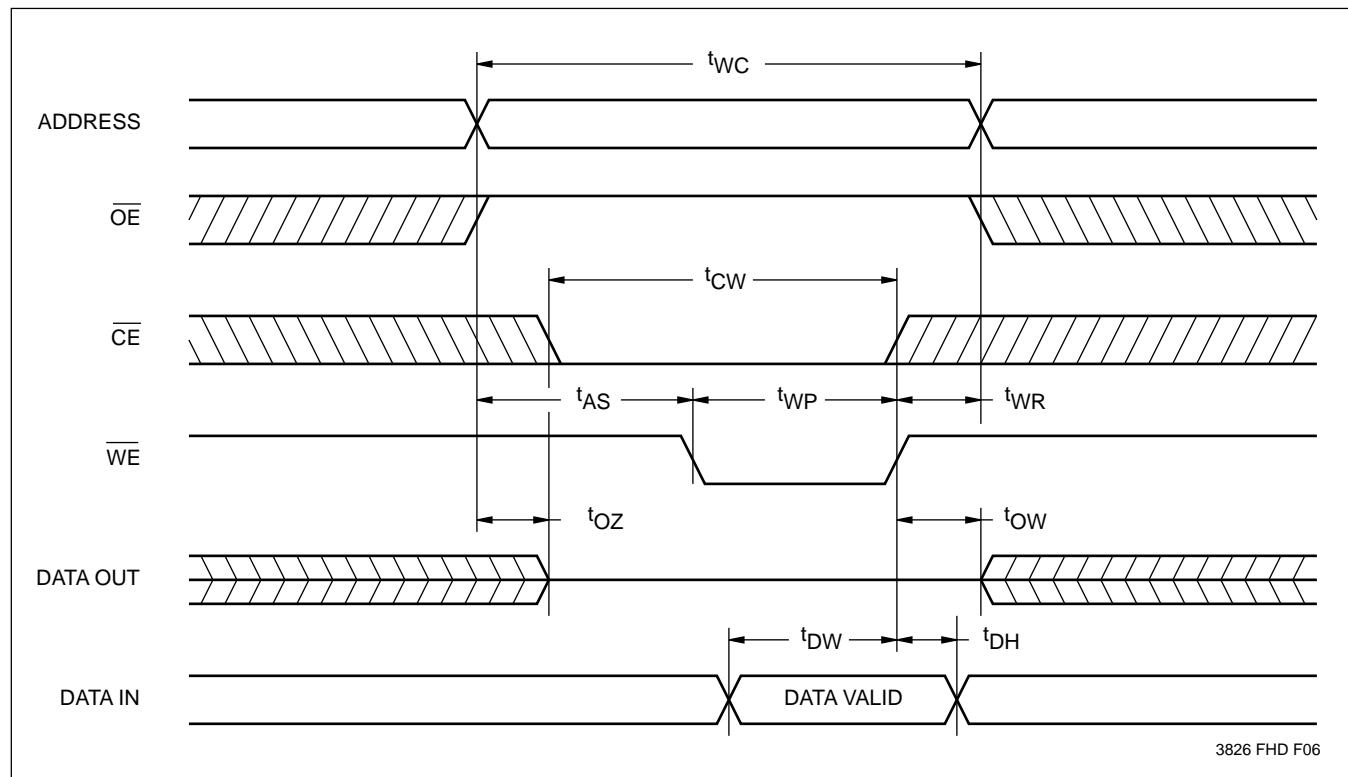
X20C16

Write Cycle Limits

Symbol	Parameter	X20C16-35		X20C16-45		X20C16-55		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
t _{WC}	Write Cycle Time	35		45		55		ns
t _{CW}	Chip Enable to End of Write Input	30		35		40		ns
t _{AS}	Address Setup Time	0		0		0		ns
t _{WP}	Write Pulse Width	30		35		40		ns
t _{WR}	Write Recovery Time	0		0		0		ns
t _{DW}	Data Setup to End of Write	15		20		25		ns
t _{DH}	Data Hold Time	3		3		3		ns
t _{WZ} ⁽⁴⁾	Write Enable to Output in High Z		15		20		25	ns
t _{OW} ⁽⁴⁾	Output Active from End of Write	5		5		5		ns
t _{OZ} ⁽⁴⁾	Output Enable to Output in High Z		15		20		25	ns

3826 PGM T11

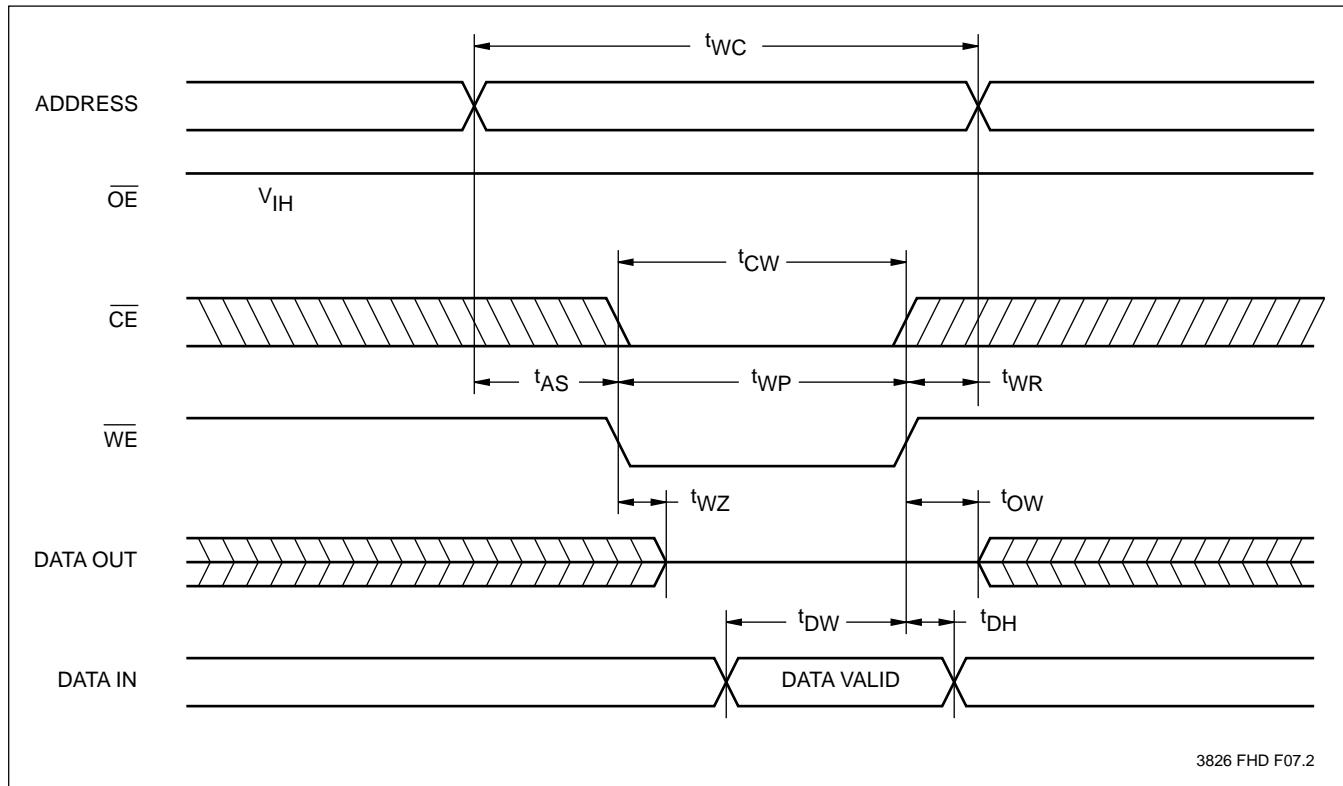
WE Controlled Write Cycle



Note: (4) t_{WZ}, t_{OW}, t_{OZ} are periodically sampled and not 100% tested.

X20C16

CE Controlled Write Cycle



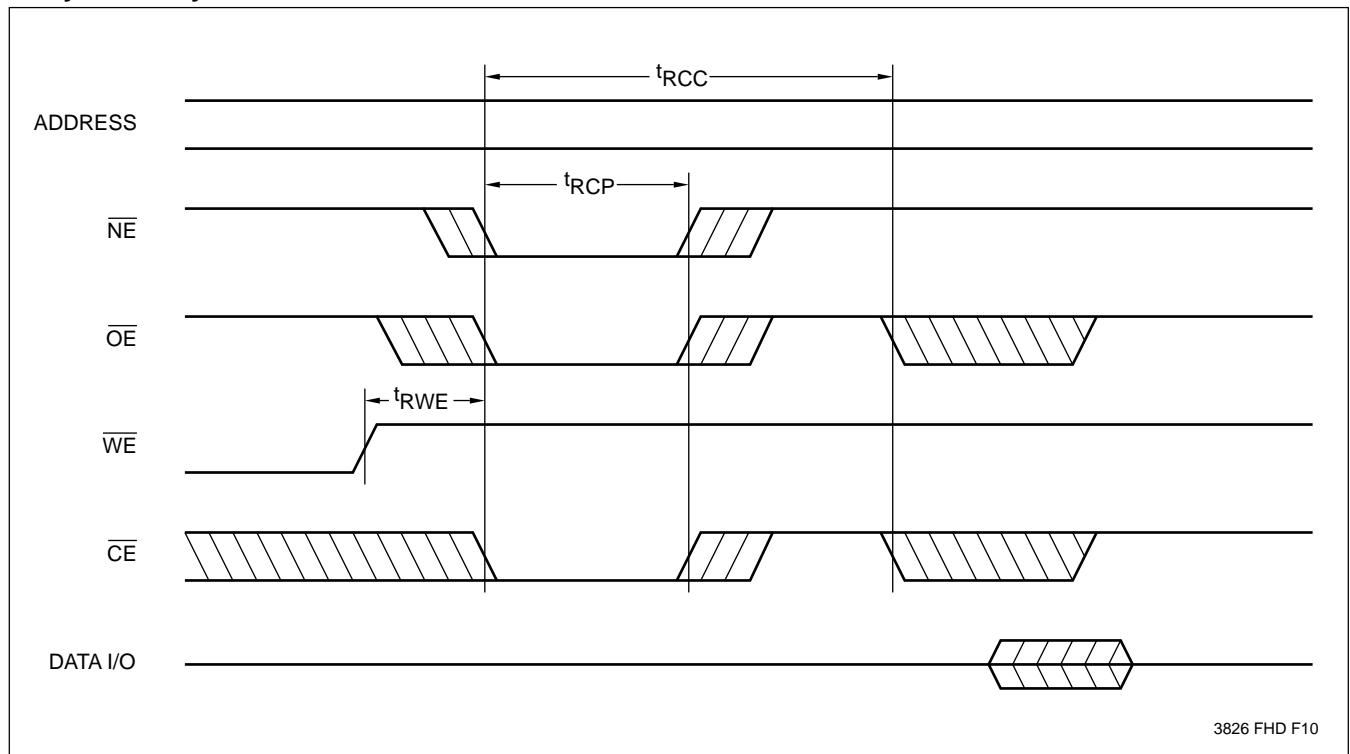
X20C16

ARRAY RECALL CYCLE LIMITS

Symbol	Parameter	X20C16-35		X20C16-45		X20C16-55		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
t_{RCC}	Array Recall Cycle Time		10		10		10	μs
$t_{RCP}^{(5)}$	Recall Pulse Width to InitiateRecall	30		40		50		ns
t_{RWE}	\overline{WE} Setup Time to \overline{NE}	0		0		0		ns

3826 PGM T13

Array Recall Cycle



Note: (5) The Recall Pulse Width (t_{RCP}) is a minimum time that \overline{NE} , \overline{OE} and \overline{CE} must be LOW simultaneously.

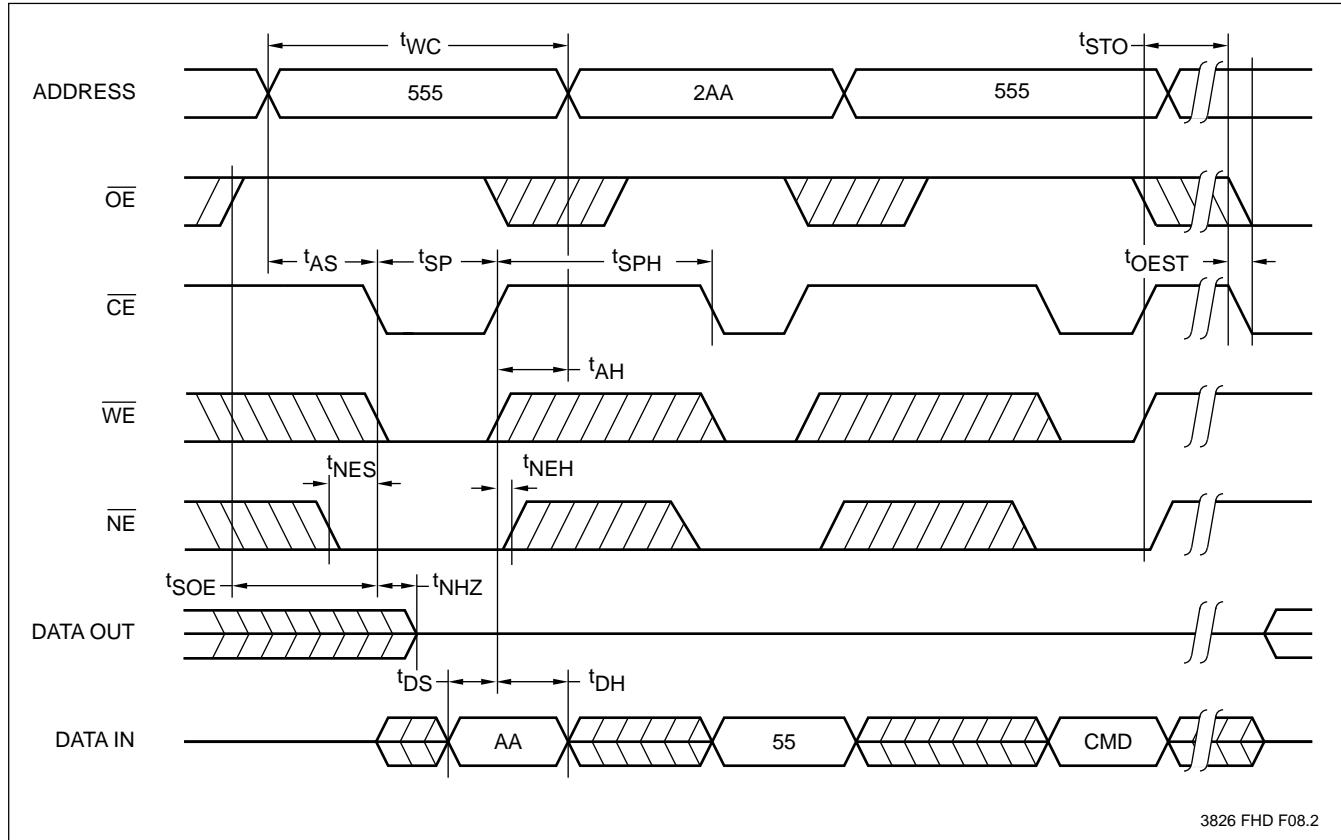
X20C16

Software Command Timing Limits

Symbol	Parameter	X20C16-35		X20C16-45		X20C16-55		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
t_{STO}	Store Cycle Time		5		5		5	ms
$t_{SP}^{(6)}$	Store Pulse Width	30		40		50		ns
t_{SPH}	Store Pulse Hold Time	35		45		55		ns
t_{WC}	Write Cycle Time	35		45		55		ns
t_{AS}	Address Setup Time	0		0		0		ns
t_{AH}	Address Hold time	0		0		0		ns
t_{DS}	Data Setup Time	15		20		25		ns
t_{DH}	Data Hold Time	3		3		3		ns
$t_{SOE}^{(7)}$	\overline{OE} Disable to Store Function	20		20		20		ns
$t_{OEEST}^{(7)}$	Output Enable from End of Store	10		10		10		ns
$t_{NHZ}^{(7)}$	Nonvolatile Enable to Output in High Z		15		20		25	ns
t_{NES}	\overline{NE} Setup Time	5		5		5		ns
t_{NEH}	\overline{NE} Hold Time	5		5		5		ns

3826 PGM T12.2

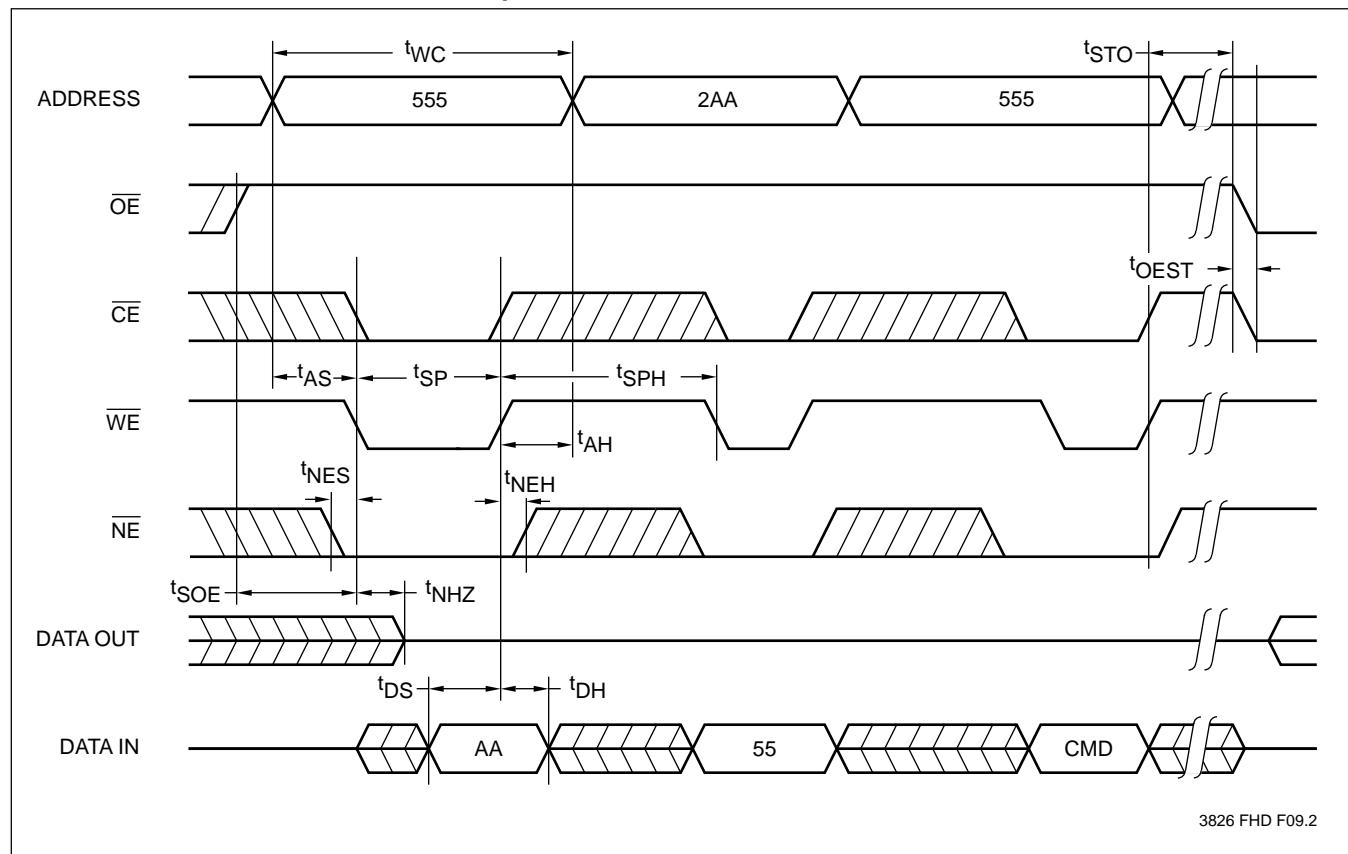
\overline{CE} Controlled Software Command Sequence



Note: (6) The Store Pulse Width (t_{SP}) is a minimum time that \overline{NE} , \overline{WE} and \overline{CE} must be LOW simultaneously.
 (7) t_{SOE} , t_{OEEST} and t_{NHZ} are periodically sampled and not 100% tested.

X20C16

WE Controlled Software Command Sequence

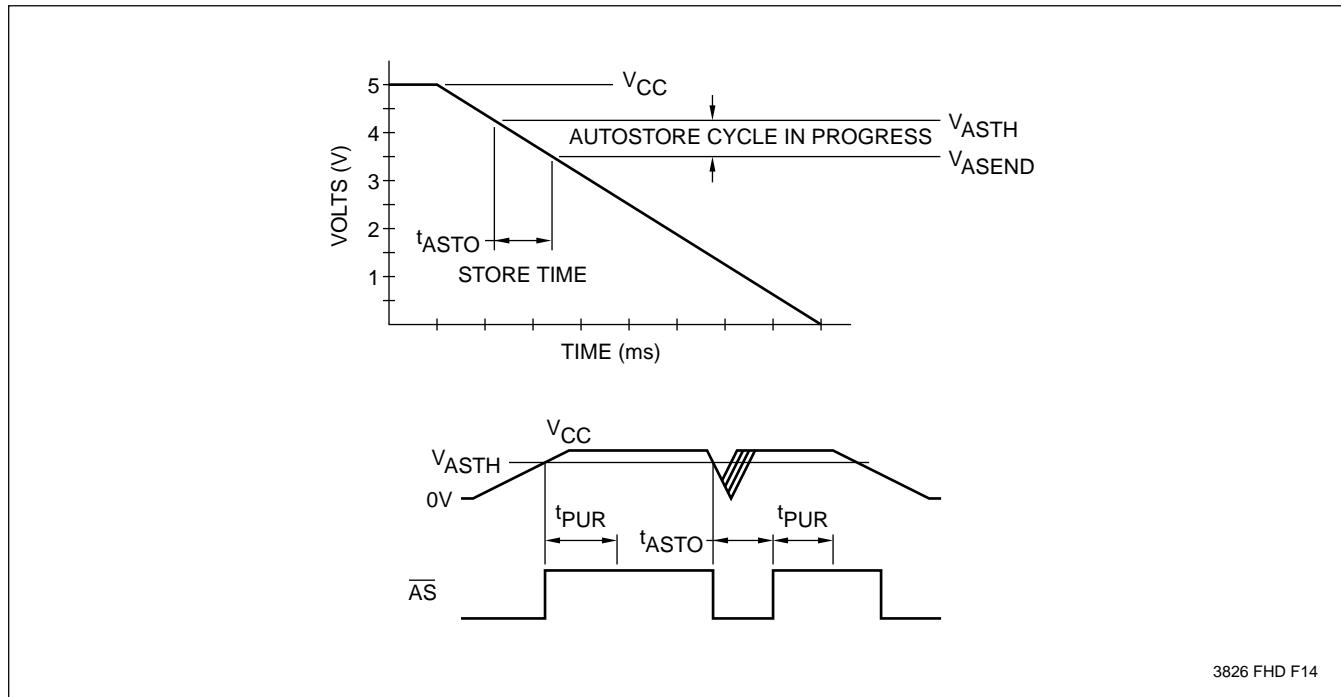


X20C16

AUTOSTORE Feature

The AUTOSTORE feature automatically saves the contents of the X20C16's static RAM to the on-board bit-for-bit shadow E²PROM at power-down. This circuitry insures that no data is lost during accidental power-downs or general system crashes, and is ideal for microprocessor caching systems, embedded software systems, and general system back-up memory.

AUTOSTORE CYCLE Timing Diagrams



3826 FHD F14

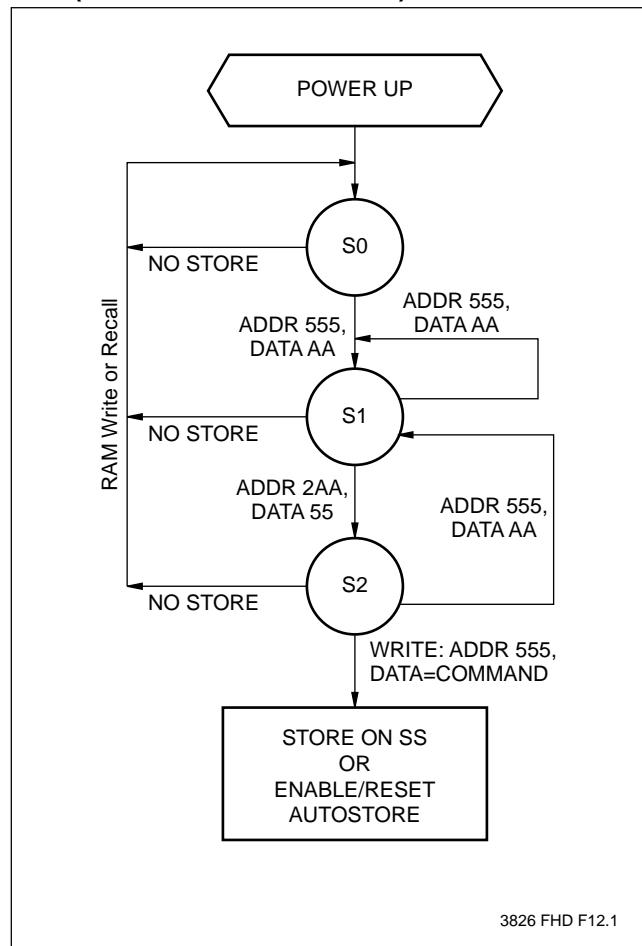
AUTOSTORE CYCLE LIMITS

Symbol	Parameter	X20C16		Units
		Min.	Max.	
t _{ASTO}	AUTOSTORE Cycle Time		2.5	ms
V _{ASTH}	AUTOSTORE Threshold Voltage	4.0	4.3	V
V _{ASEND}	AUTOSTORE Cycle End Voltage	3.5		V

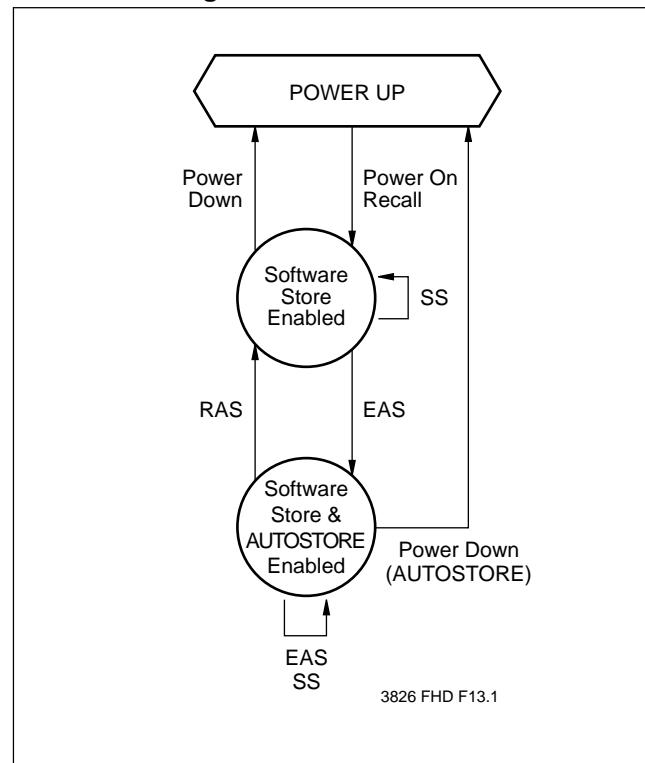
3826 PGM T15

X20C16

SDP (Software Data Protection)



Store State Diagram



SOFTWARE DATA PROTECTION COMMANDS

Command		Data
EAS	Enable AUTOSTORE	CC[H]
RAS	Reset AUTOSTORE	CD[H]
SS	Software Store	33[H]

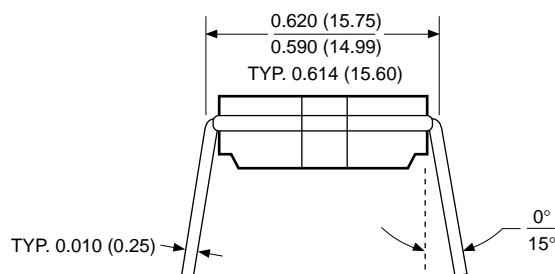
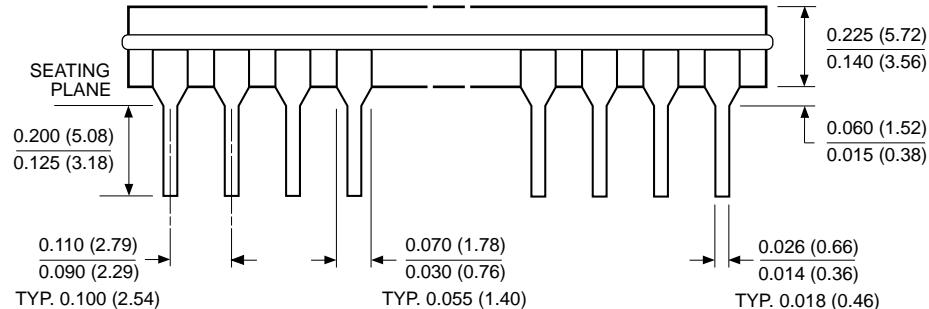
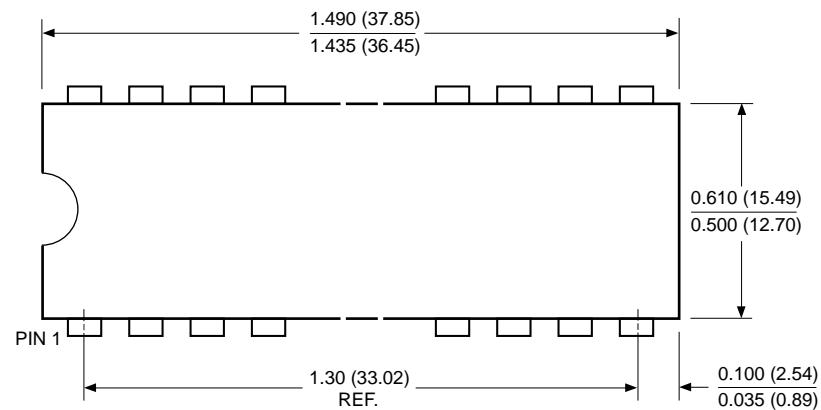
3826 PGM T14.1

NOTES

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PACKAGING INFORMATION

28-LEAD HERMETIC DUAL IN-LINE PACKAGE TYPE D



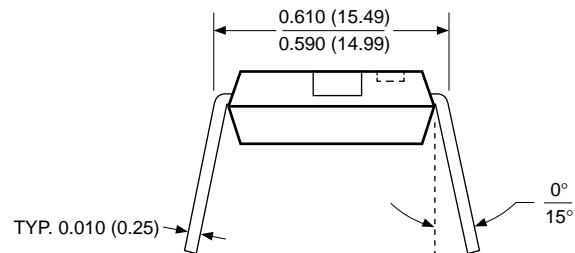
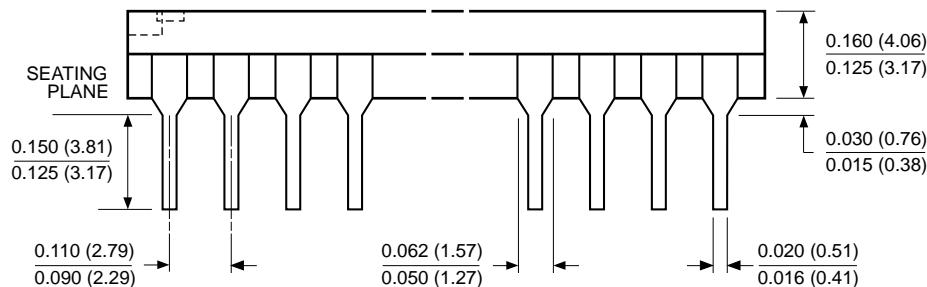
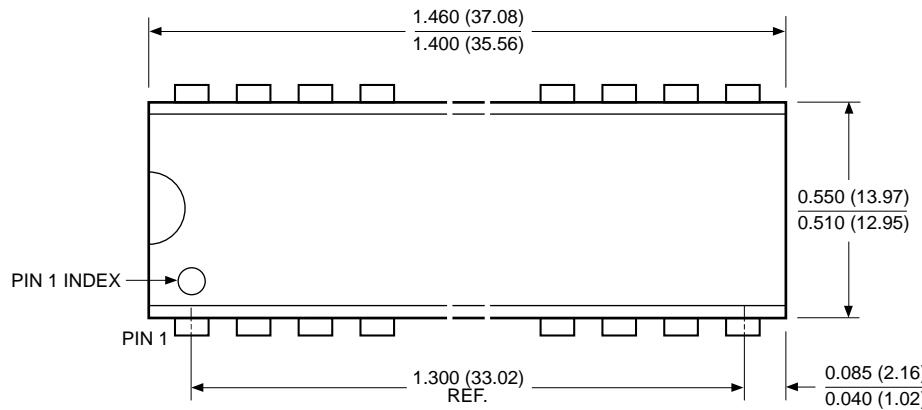
NOTE: ALL DIMENSIONS IN INCHES (IN PARENTHESES IN MILLIMETERS)

3926 FHD F08

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PACKAGING INFORMATION

28-LEAD PLASTIC DUAL IN-LINE PACKAGE TYPE P



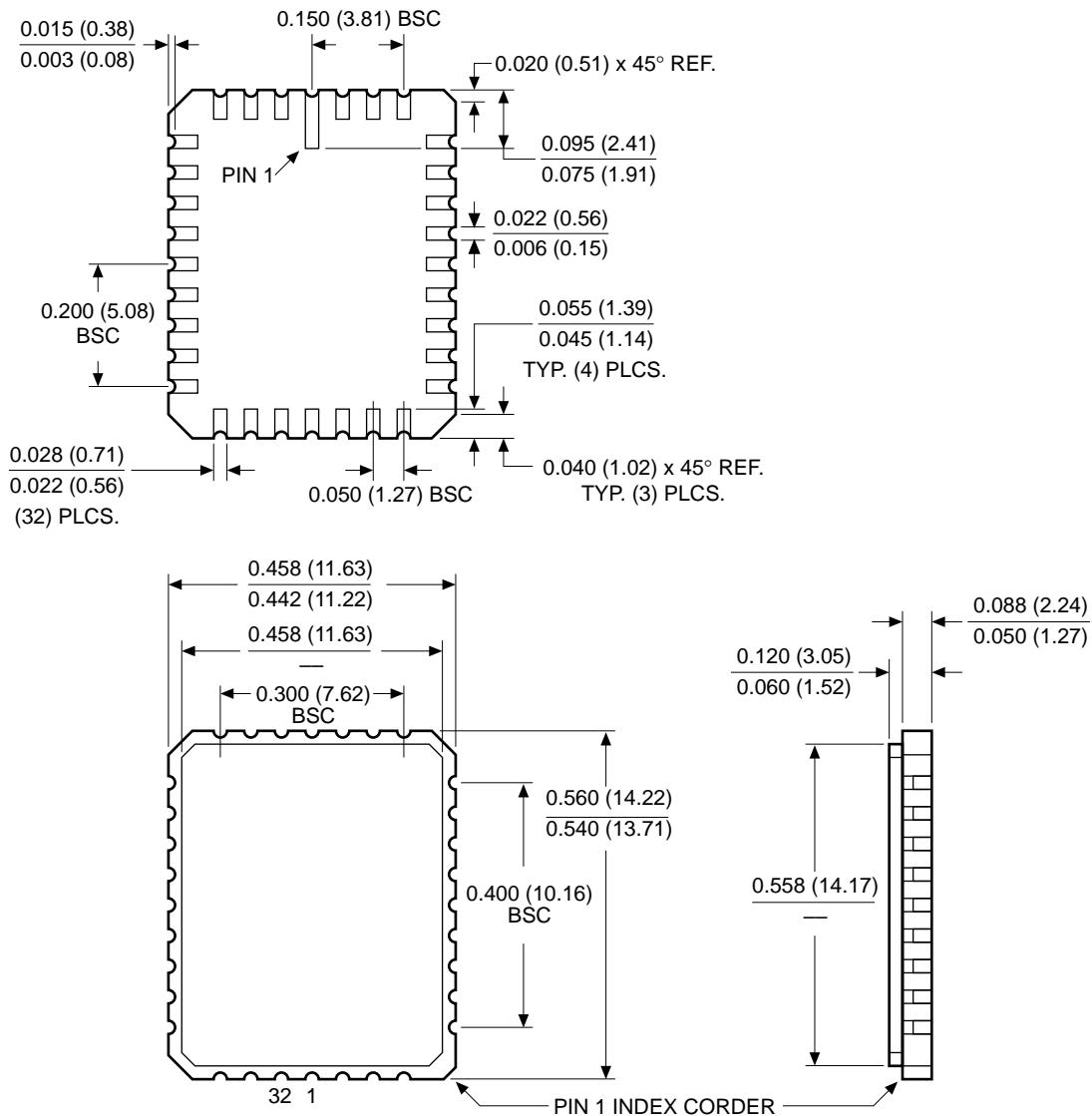
NOTE: ALL DIMENSIONS IN INCHES (IN PARENTHESES IN MILLIMETERS)

3926 FHD F04

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PACKAGING INFORMATION

32-PAD CERAMIC LEADLESS CHIP CARRIER PACKAGE TYPE E



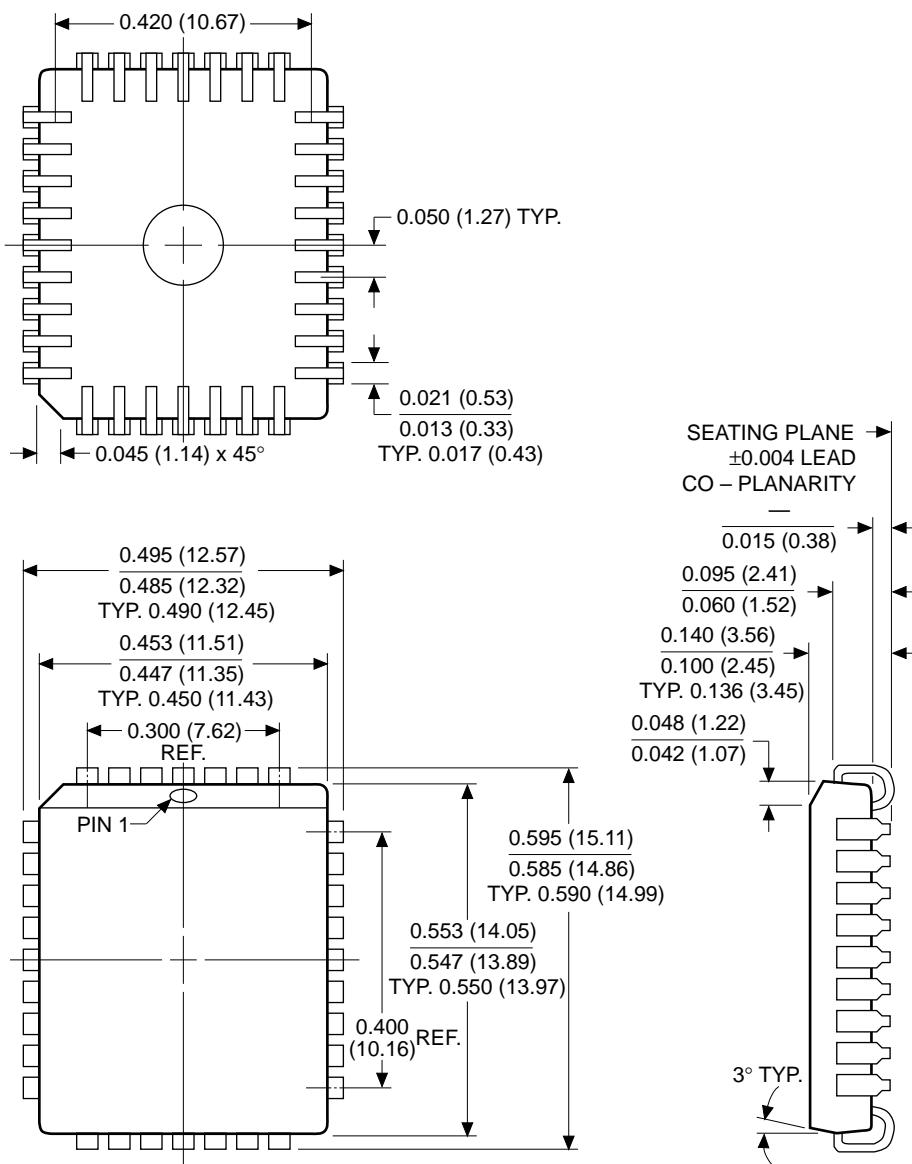
NOTE:

1. ALL DIMENSIONS IN INCHES (IN PARENTHESES IN MILLIMETERS)
2. TOLERANCE: $\pm 1\%$ NTL ± 0.005 (0.127)

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PACKAGING INFORMATION

32-LEAD PLASTIC LEADED CHIP CARRIER PACKAGE TYPE J



NOTES:

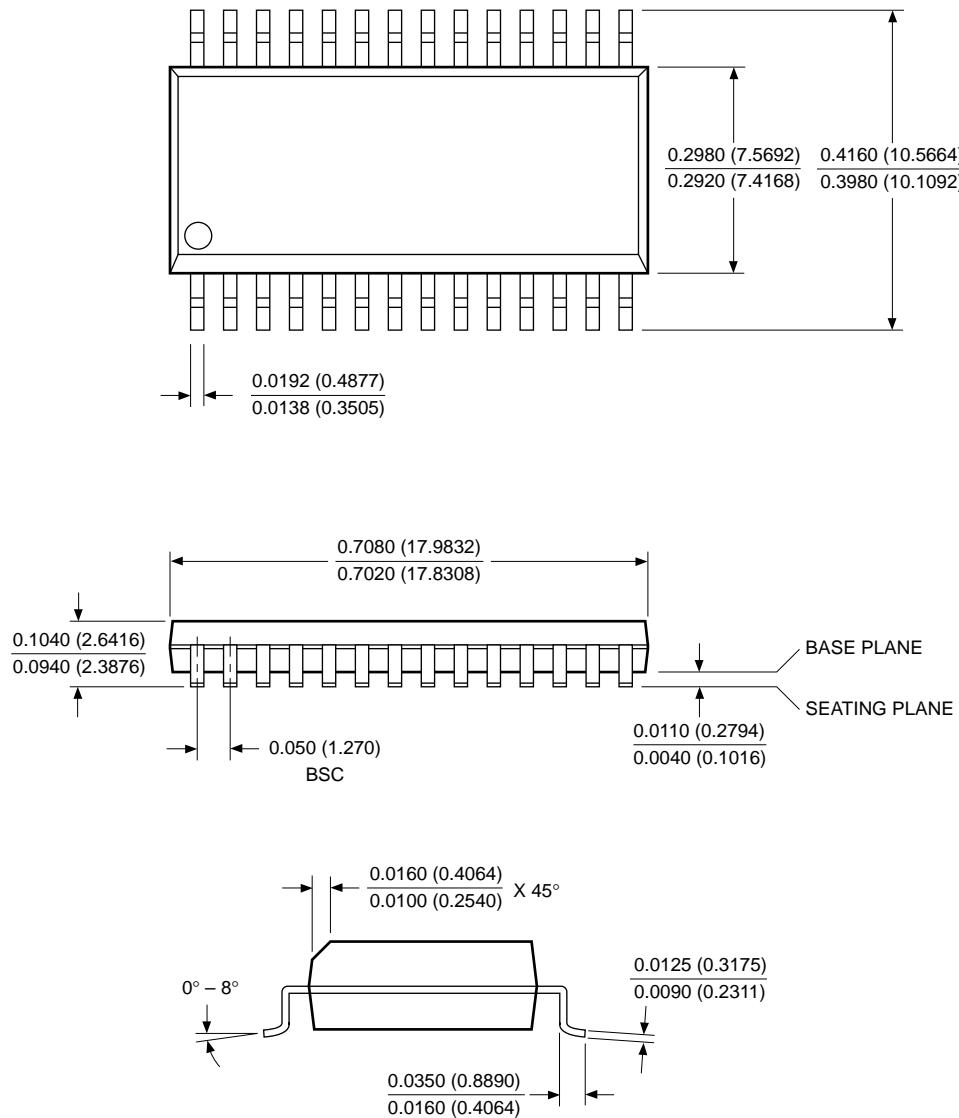
- ALL DIMENSIONS IN INCHES (IN PARENTHESES IN MILLIMETERS)
- DIMENSIONS WITH NO TOLERANCE FOR REFERENCE ONLY

3926 FHD F13

X20C16

PACKAGING INFORMATION

28-LEAD PLASTIC SMALL OUTLINE GULL WING PACKAGE TYPE S

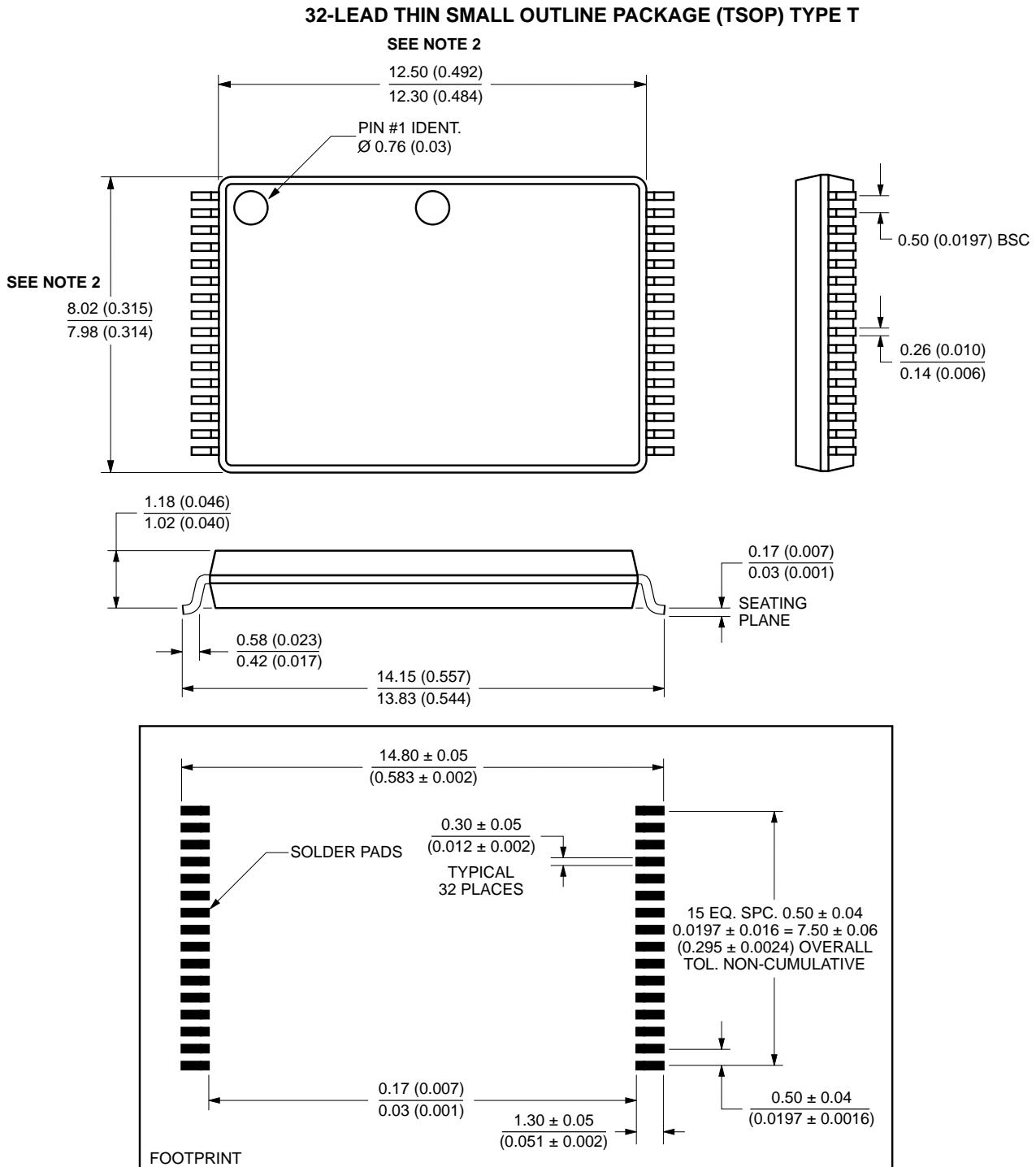


NOTES:

1. ALL DIMENSIONS IN INCHES (IN PARENTHESES IN MILLIMETERS)
2. FORMED LEAD SHALL BE PLANAR WITH RESPECT TO ONE ANOTHER WITHIN 0.004 INCHES
3. BACK EJECTOR PIN MARKED "KOREA"
4. CONTROLLING DIMENSION: INCHES (MM)

X20C16

PACKAGING INFORMATION



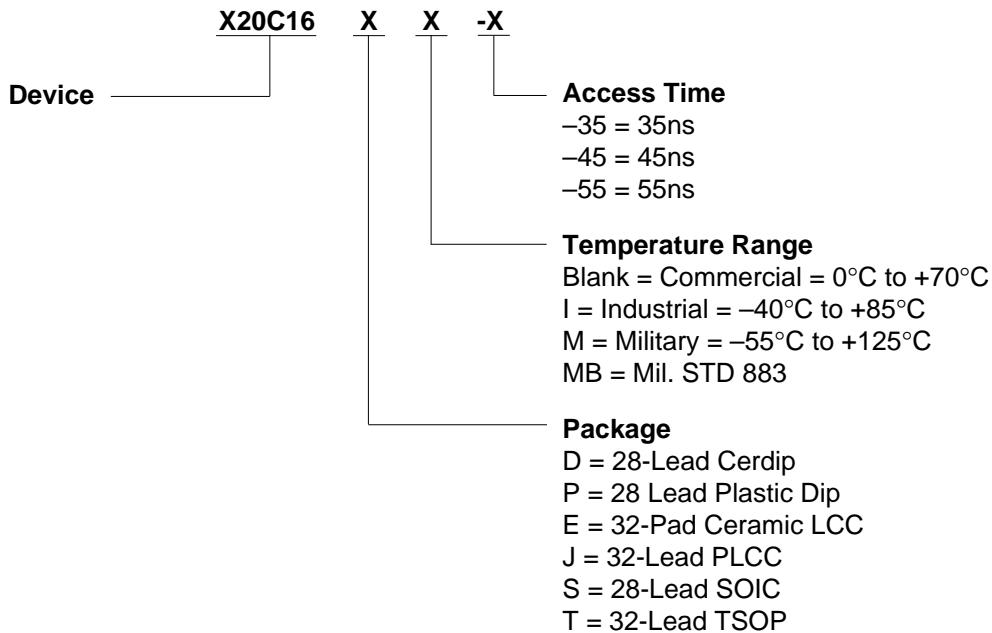
NOTE:

1. ALL DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES IN PARENTHESES).

3926 ILL F38.1

X20C16

ORDERING INFORMATION



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Devices sold by Xicor, Inc. are covered by the warranty and patent indemnification provisions appearing in its Terms of Sale only. Xicor, Inc. makes no warranty, express, statutory, implied, or by description regarding the information set forth herein or regarding the freedom of the described devices from patent infringement. Xicor, Inc. makes no warranty of merchantability or fitness for any purpose. Xicor, Inc. reserves the right to discontinue production and change specifications and prices at any time and without notice.

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LIFE RELATED POLICY

In situations where semiconductor component failure may endanger life, system designers using this product should design the system with appropriate error detection and correction, redundancy and back-up features to prevent such an occurrence.

Xicor's products are not authorized for use as critical components in life support devices or systems.

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

NOTES

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U.S. SALES OFFICES

Corporate Office

Xicor Inc.
1511 Buckeye Drive
Milpitas, CA 95035
Phone: 408/432-8888
Fax: 408/432-0640
E-mail: info@smtpgate.xicor.com

Northeast Region

Xicor Inc.
1344 Main Street
Waltham, MA 02154
Phone: 617/899-5510
Fax: 617/899-6808
E-mail: xicor-ne@smtpgate.xicor.com

Southeast Region

Xicor Inc.
100 E. Sybelia Ave.
Suite 355
Maitland, FL 32751
Phone: 407/740-8282
Fax: 407/740-8602
E-mail: xicor-se@smtpgate.xicor.com

Mid-Atlantic Region

Xicor Inc.
50 North Street
Danbury, CT 06810
Phone: 203/743-1701
Fax: 203/794-9501
E-mail: xicor-ma@smtpgate.xicor.com

North Central Region

Xicor Inc.
810 South Bartlett Road
Suite 103
Streamwood, IL 60107
Phone: 708/372-3200
Fax: 708/372-3210
E-mail: xicor-nc@smtpgate.xicor.com

South Central Region

Xicor Inc.
11884 Greenville Ave.
Suite 102
Dallas, TX 75243
Phone: 214/669-2022
Fax: 214/644-5835
E-mail: xicor-sc@smtpgate.xicor.com

Southwest Region

Xicor Inc.
4100 Newport Place Drive
Suite 710
Newport Beach, CA 92660
Phone: 714/752-8700
Fax: 714/752-8634
E-mail: xicor-sw@smtpgate.xicor.com

Northwest Region

Xicor Inc.
2700 Augustine Drive
Suite 219
Santa Clara, CA 95054
Phone: 408/292-2011
Fax: 408/980-9478
E-mail: xicor-nw@smtpgate.xicor.com

INTERNATIONAL SALES OFFICES

EUROPE

Northern Europe
Xicor Ltd.
Grant Thornton House
Witan Way
Witney
Oxford OX8 6FE
UK
Phone: (44) 1933.700544
Fax: (44) 1933.700533
E-mail: xicor-uk@smtpgate.xicor.com

Central Europe

Xicor GmbH
Technopark Neukeferloh
Bretonischer Ring 15
85630 Grasbrunn bei Muenchen
Germany
Phone: (49) 8946.10080
Fax: (49) 8946.05472
E-mail: xicor-gm@smtpgate.xicor.com

ASIA/PACIFIC

Japan
Xicor Japan K.K.
Suzuki Building, 4th Floor
1-6-8 Shinjuku, Shinjuku-ku
Tokyo 160, Japan
Phone: (81) 3322.52004
Fax: (81) 3322.52319
E-mail: xicor-jp@smtpgate.xicor.com

Mainland China

Taiwan/Hong Kong
Xicor Inc.
4100 Newport Place Drive
Suite 710
Newport Beach, CA 92660
Phone: 714/752-8700
Fax: 714/752-8634
E-mail: xicor-sw@smtpgate.xicor.com

Singapore/Malaysia/India

Xicor Inc.
2700 Augustine Drive
Suite 219
Santa Clara, CA 95054
Phone: 408/292-2011
Fax: 408/980-9478
E-mail: xicor-nw@smtpgate.xicor.com

Korea

Xicor Korea
27th Fl., Korea World Trade Ctr.
159, Samsung-dong
Kangnam Ku
Seoul 135-729
Korea
Phone: (82) 2551.2750
Fax: (82) 2551.2710
E-mail: xicor-ka@smtpgate.xicor.com

() = Country Code

Xicor product information is available at:

<http://www.xicor.com>